TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

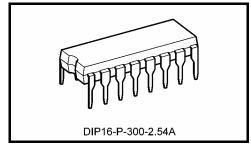
TC4521BP

TC4521BP 24-Stage Frequency Divider

TC4521BP is frequency divider consisting of 24 stages of flip-flop. The input section is equipped with an inverter to enable to use either RC oscillator circuit or crystal oscillator circuit and to accept pulse from external clock source.

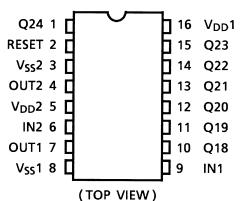
Each flip-flop is inverted by the falling edge of the output of previous stage flip-flop and this can count up to the maximum of $2^{24} = 16,777,216$.

Since six outputs, 2^{18} , 2^{19} , 2^{20} , 2^{21} , 2^{22} , and 2^{23} are available besides of 2^{24} , adjustment of frequency divided output can be achieved.



Weight: 1.00 g (typ.)

Pin Assignment

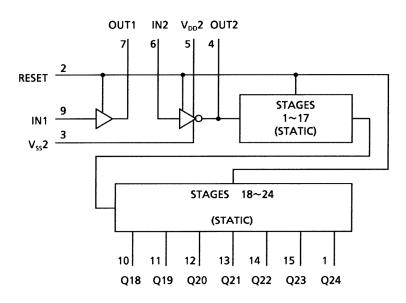


Count Capacity

Output	Count Capacity			
Q18	$2^{18} = 262,144$			
Q19	$2^{19} = 524,288$			
Q20	2 ²⁰ = 1,048,576			
Q21	$2^{21} = 2,097,152$			
Q22	$2^{22} = 4,194,304$			
Q23	$2^{23} = 8,388,608$			
Q24	$2^{24} = 16,777,216$			

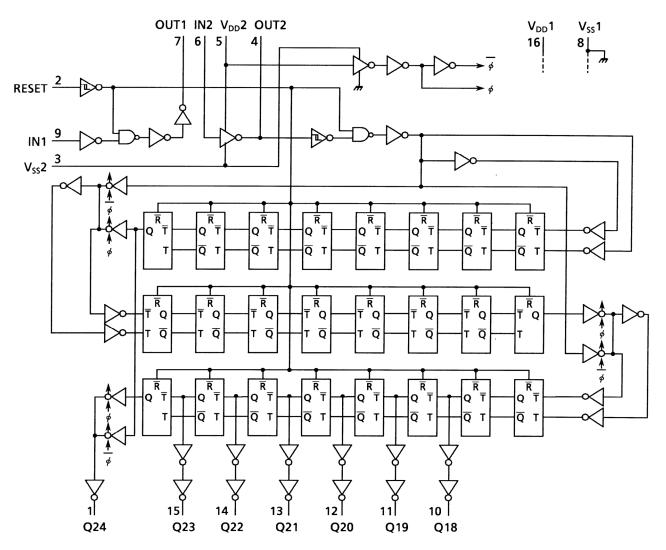
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Block Diagram

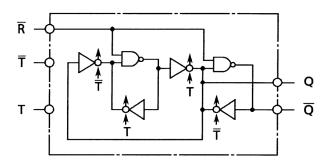


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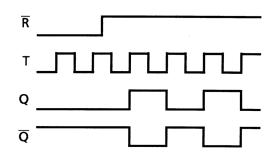
Logic Diagram



Internal Flip Flop Logic Diagram



Flip Flop Timing Chart



Absolute Maximum Ratings (Note)

Characteristics	Symbol	Rating	Unit
DC supply voltage	V _{DD} 1	$V_{SS}1 - 0.5 V_{SS}1 + 20$	V
DC supply voltage	V _{DD} 2	V _{SS} 1 - 0.5~V _{DD} 1 + 0.5	v
put voltage V _{IN}		$V_{SS}1 - 0.5 \text{-} V_{DD}1 + 0.5$	V
Output voltage	V _{OUT}	$V_{SS}1 - 0.5 \text{-} V_{DD}1 + 0.5$	V
DC input current	I _{IN}	±10	mA
Power dissipation	PD	300	mW
Operating temperature range	T _{opr}	-40~85	°C
Storage temperature range	T _{stg}	-65~150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Operating Ranges (V_{SS}1 = V_{SS}2 = 0 V) (Note)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
DC supply voltage	V _{DD} 1, V _{DD} 2	—	3	_	18	V
Input voltage	V _{IN}	_	0		V _{DD} 1	V

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either V_{DD} or V_{SS} .

Static Electrical Characteristics ($V_{SS}1 = V_{SS}2 = 0 V$, $V_{DD}1 = V_{DD}2$)

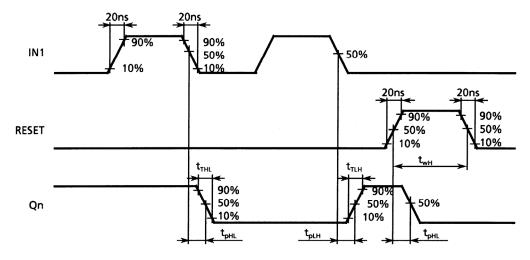
Svn		Sym-	Test Condition		-40°C		25°C			85°C			
Charac	teristics	bol		V _{DD} (V)	Min	Max	Min	Тур.	Max	Min	Max	Unit	
High-level output VOH		I _{OUT} < 1 μΑ	5	4.95	_	4.95	5.00	_	4.95	_			
		V _{OH}	$ 1_{OUT} < 1 \mu A$ $V_{IN} = V_{SS}, V_{DD}$	10	9.95	—	9.95	10.00	—	9.95	—	V	
Ŭ			VIN – VSS, VDD	15	14.95	_	14.95	15.00	_	14.95	_		
			I _{OUT} < 1 μΑ	5		0.05		0.00	0.05		0.05		
Low-level voltage	output	V _{OL}	$V_{IN} = V_{SS}, V_{DD}$	10	_	0.05		0.00	0.05	—	0.05	V	
Ŭ			VIN – VSS, VDD	15	_	0.05		0.00	0.05	—	0.05		
			V _{OH} = 4.6 V	5	-0.61		-0.51	-1.0		-0.42			
			$V_{OH} = 2.5 V$	5	-2.5	—	-2.1	-4.0	—	-1.7	—		
Output hig	h current	IOH	V _{OH} = 9.5 V	10	-1.5	—	-1.3	-2.2	—	-1.1	—	mA	
			V _{OH} = 13.5 V	15	-4.0	—	-3.4	-9.0	—	-2.8	—		
			$V_{IN}=V_{SS},V_{DD}$										
			$V_{OL} = 0.4 V$	5	0.61	—	0.51	1.2	—	0.42	—		
	v current	le.	$V_{OL} = 0.5 V$	10	1.5	—	1.3	3.2	—	1.1	—	mA	
Output low current	IOL	V _{OL} = 1.5 V	15	4.0	—	3.4	12.0	—	2.8	—	ША		
			$V_{IN}=V_{SS},V_{DD}$										
			$V_{OUT} = 0.5 V, 4.5 V$	5	3.5		3.5	2.75		3.5			
Input high	voltago	VIH	V _{OUT} = 1.0 V, 9.0 V	10	7.0	—	7.0	5.5	—	7.0	—	V	
input nigh	voltage	VIН	$V_{OUT} = 1.5 V, 13.5 V$	15	11.0	—	11.0	8.25	—	11.0	—	v	
			$ I_{OUT} < 1 \ \mu A$										
			$V_{OUT} = 0.5 V, 4.5 V$	5		1.5		2.25	1.5		1.5		
Input low y	voltago	VIL	V _{OUT} = 1.0 V, 9.0 V	10	—	3.0		4.5	3.0		3.0	v	
Input low voltage		۷IL	V _{OUT} = 1.5 V, 13.5 V	15	—	4.0		6.75	4.0		4.0	v	
			$ I_{OUT} < 1 \ \mu A$										
Input ^{"H"}	"H" level	IIН	V _{IH} = 18 V	18		0.1		10 ⁻⁵	0.1		1.0	μA	
current	"L" level	١ _{١L}	$V_{IL} = 0 \ V$	18	_	-0.1		-10 ⁻⁵	-0.1	—	-1.0	μη	
				5	_	5		0.005	5		150		
Quiescent current	Quiescent supply current		$V_{IN} = V_{SS}, V_{DD}$	10	—	10		0.010	10		300	μA	
ourient			(Note)	15	—	20		0.015	20		600		

Note: All valid input combinations.

Dynamic Electrical Characteristics (Ta = 25°C, V_{SS} 1 = V_{SS} 2 = 0 V, V_{DD} 1 = V_{DD} 2, C_L = 50 pF)

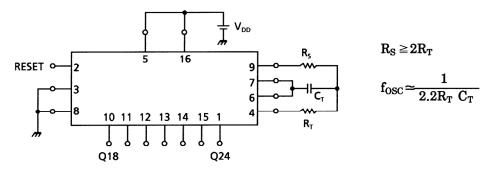
Characteristics	Symbol	Test Condition	Min	Turp	Max	Unit	
Characteristics	Symbol		V _{DD} (V)	IVIIII	Тур.	Max	Unit
Output transition time			5		70	200	
(low to high)	t _{TLH}	—	10	—	35	100	ns
			15	—	30	80	
Output transition time			5	_	70	200	
Output transition time	t _{THL}	_	10	—	35	100	ns
(high to low)			15	—	30	80	
Dranagation dalay time	4		5	_	1.1	9.0	
Propagation delay time	t _{pLH}	_	10	—	0.5	3.5	μS
(IN2-Q18)	t _{pHL}		15	—	0.3	2.7	
Dranagation dalay time	4		5	_	1.4	12	
Propagation delay time	t _{pLH}	_	10	—	0.6	4.5	μS
(IN2-Q24)	t _{pHL}		15	—	0.4	3.5	
			5	_	220	2600	
Propagation delay time	t _{pHL}	—	10	_	100	1000	ns
(RESET-Qn)			15	—	70	750	
			5	3	9.5	_	
Max clock frequency	f _{CL}	_	10	6	17.5		MHz
			15	8	23.5		
Max clock input rise time	4		5				
	t _{rCL}	—	10	No limit			μS
Max clock input fall time	t _{fCL}		15				
			5	_	55	385	
Min clock pulse width	t _W	—	10	—	25	150	ns
			15	_	16	120	
Min pulse width			5	_	60	385	
Min pulse width	t _{WH}	—	10	—	26	150	ns
(RESET)			15	—	20	120	
Input capacitance	C _{IN}	_			5	7.5	pF

Waveforms for Measurement of Dynamic Characteristics

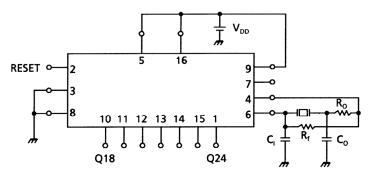


Application Circuit

When CR Oscillation is Used as Time Reference



When Crystal Oscillation is Used as the Time Reference

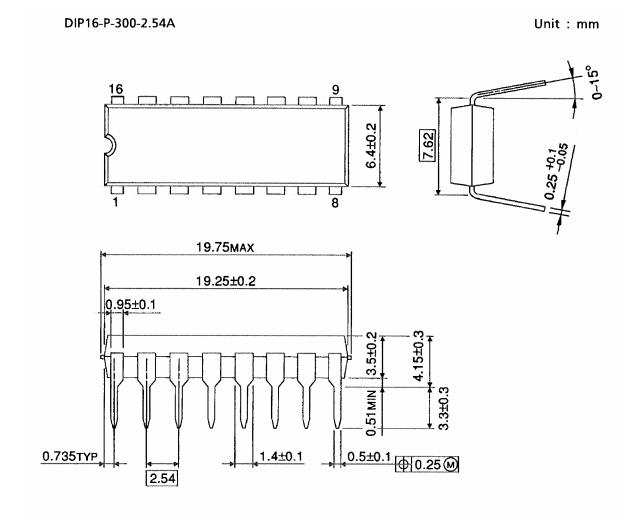


Typical Data

X'tal (Hz)	C _I , C _O (pF)	R _O (Ω)
32.768 k	23	500 k
100 k	60	100 k
1 M	45~50	100
4.194304 M	12~15	0

 $R_f=10~M\Omega$

Package Dimensions



Weight: 1.00 g (typ.)

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20070701-EN GENERAL

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